

U.S. Department of Commerce, Patent and Trademark Office		Atty Docket No.	Serial No.
		M-799-4C US	087857005 UNKNOWN
INFORMATION DISCLOSURE STATEMENT BY APPLICANT		Applicant	
(Use several sheets if necessary)		Constantin Bulucea, et al.	
		Filing Date	Group
		Herewith	
		2508	

U.S. Patent Documents

*Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
AA						
AB						
AC						
AD						
AE						
AF						
AG						
AH						
AI						
AJ						
AK						

Foreign Patent Documents

	Document	Date	Country	Class	Subclass	Yes	Translation
AL							
AM							
AN							
AO							
AP							

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

AR	"Design of New Structural High Breakdown Voltage V-MOSFET--Static Shield V-MOSFET", Kuniharu Katoh and Yuuki Shimada, Electronics and Communications in Japan, Vol. 66-C, No. 6, 1983, pp. 95-105.
AS	"U-MOS Power FET", Daisuke Ueda, Hiromitsu, Takagi, Kazuyoshi Kitamura, Goryo Haggio and Masaru Nahara, National Technical Report, Vol. 29, No. 2, April, 1983, pp. 143-150.
AT	
Examiner	Date Considered

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.